## 315MHz/433MHz ASK Superheterodyne Receiver with Extended Dynamic Range

### **Absolute Maximum Ratings**

V <sub>DD5</sub> to AGND	0.3V to +6.0V
AVDD to AGND	0.3V to +4.0V
DVDD to DGND	0.3V to +4.0V
AGND to DGND	0.1V to +0.1V
IRSEL, DATAOUT, XTALSEL, AGCDIS	S,
PWRDN to AGND	0.3V to (V <sub>DD5</sub> + 0.3V)
All Other Pins to AGND	

Continuous Power Dissipation (T <sub>A</sub> = +70°C)
28-Pin TSSOP (derate 12.8mW/°C above +70°C).1025.6mW
32-Pin Thin QFN (derate 21.3mW/°C
above +70°C)1702.1mW
Operating Temperature Ranges
MAX1473E40°C to +85°C
Storage Temperature Range60°C to +150°C
Lead Temperature (soldering 10s)+300°C
Soldering Temperature (reflow)+260°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### **DC Electrical Characteristics (3.3V Operation)**

(*Typical Application Circuit*,  $AV_{DD} = DV_{DD} = V_{DD5} = 3.0V$  to 3.6V, no RF signal applied,  $T_A = -40^{\circ}C$  to +85°C, unless otherwise noted. Typical values are at  $V_{DD} = 3.3V$  and  $T_A = +25^{\circ}C$ .) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	MAX	UNITS
Supply Voltage	V <sub>DD</sub>	3.3V nominal supply		3.0	3.3	3.6	V
Supply Current			f <sub>RF</sub> = 315MHz		5.2	6.23	mA
Supply Current	I <sub>DD</sub>	$V_{PWRDN} = V_{DD5}$	f <sub>RF</sub> = 433MHz		5.8	6.88	mA
Chutdown Cuprily Current	I	V <sub>PWRDN</sub> = 0V,	f <sub>RF</sub> = 315MHz		1.6		μA
Shutdown Supply Current	IPWRDN	V <sub>XTALSEL</sub> = 0V	f <sub>RF</sub> = 433MHz		2.5	5.3	
Input Voltage Low	VIL					0.4	V
Input Voltage High	VIH			AV <sub>DD</sub> - 0	.4		V
Input Logic Current High	IIH				10		μA
		f <sub>RF</sub> = 433MHz, V <sub>IRS</sub>	<sub>SEL</sub> = AV <sub>DD</sub>	AV <sub>DD</sub> - 0	.4		
Image Reject Select (Note 2)		f <sub>RF</sub> = 375MHz, V <sub>IRSEL</sub> = AV <sub>DD</sub> /2		1.1	ŀ	W <sub>DD</sub> - 1.5	V
		f <sub>RF</sub> = 315MHz, V <sub>IRS</sub>	SEL = 0V			0.4	
DATAOUT Voltage Output Low	V <sub>OL</sub>	- R <sub>L</sub> = 5kΩ				0.4	V
DATAOUT Voltage Output High	V <sub>OH</sub>			V <sub>DD5</sub> - 0	.4		V

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### **Electrical Characteristics (5V Operation)**

(*Typical Application Circuit*,  $V_{DD5}$  = 4.5V to 5.5V,  $AV_{DD}$  =  $DV_{DD}$  = ~3.2V, no RF signal applied,  $T_A$  = -40°C to +85°C, unless otherwise noted. Typical values are at  $V_{DD}$  = 5.0V and  $T_A$  = +25°C.) (Note 1)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP	МАХ	UNITS
Supply Voltage	V <sub>DD</sub>	5.0V nominal supply		4.5	5.0	5.5	V
Community Community			f <sub>RF</sub> = 315MHz		5.2	6.04	0
Supply Current	DD	$V_{\overline{PWRDN}} = V_{DD5}$	f <sub>RF</sub> = 433MHz		5.7	6.76	mA
Chutdaum Currely Current		V <sub>PWRDN</sub> = 0V,	f <sub>RF</sub> = 315MHz		2.3		μA
Shutdown Supply Current	IPWRDN	VXTALSEL = 0V	f <sub>RF</sub> = 433MHz		2.8	6.2	
Input Voltage Low	VIL					0.4	V
Input Voltage High	VIH			AV <sub>DD</sub> - 0	.4		V
Input Logic Current High	IIH				10		μA
		f <sub>RF</sub> = 433MHz, V <sub>IRS</sub>	SEL = AV <sub>DD</sub>	AV <sub>DD</sub> - 0	.4		
Image Reject Select (Note 2)		f <sub>RF</sub> = 375MHz, V <sub>IRSEL</sub> = AV <sub>DD</sub> /2		1.1	A	V <sub>DD</sub> - 1.5	V
		f <sub>RF</sub> = 315MHz, V <sub>IRS</sub>	SEL = 0V			0.4	
DATAOUT Voltage Output Low	V <sub>OL</sub>	- R <sub>L</sub> = 5kΩ				0.4	V
DATAOUT Voltage Output High	V <sub>OH</sub>			V <sub>DD5</sub> - 0	4		V

#### **AC Electrical Characteristics**

(*Typical Application Circuit*,  $AV_{DD} = DV_{DD} = V_{DD5} = 3.0V$  to 3.6V, all RF inputs are referenced to 50 $\Omega$ , f<sub>RF</sub> = 315MHz, T<sub>A</sub> = -40°C to +85°C, unless otherwise noted. Typical values are at V<sub>DD</sub> = 3.3V and T<sub>A</sub> = +25°C.) (Note 1).

PARAMETER	SYMBOL	COND	MIN	ТҮР	MAX	UNITS	
GENERAL CHARACTERISTICS				L.			
Startup Time	t <sub>ON</sub>	Time for valid signal detection after V <sub>PWRDN</sub> = V <sub>OH</sub>			250		μs
Receiver Input Frequency	f <sub>RF</sub>					450	MHz
Maximum Receiver Input Level	P <sub>RFIN_MAX</sub>	Modulation depth >	18dB		0		dBm
Sensitivity (Note 3)	P <sub>RFIN_MIN</sub>	Peak power level			-114		dBm
					8		dB
AGC Hysteresis		LNA gain from low to	nign		150		ms
LNA IN HIGH-GAIN MODE							
Power Gain					16		dB
			f <sub>RF</sub> = 433MHz		1 - j3.4		
Input Impedance (Note 4)	Z <sub>IN_LNA</sub>	Normalized to $50\Omega$	f <sub>RF</sub> = 375MHz	1 - j3.9			
			f <sub>RF</sub> = 315MHz		1 - j4.7		
1dB Compression Point	P1dB <sub>LNA</sub>				-22		dBm
Input-Referred 3rd-Order Intercept	IIP3 <sub>LNA</sub>				-12		dBm

## 315MHz/433MHz ASK Superheterodyne Receiver with Extended Dynamic Range

### **AC Electrical Characteristics (continued)**

(*Typical Application Circuit*,  $AV_{DD} = DV_{DD} = V_{DD5} = 3.0V$  to 3.6V, all RF inputs are referenced to  $50\Omega$ ,  $f_{RF} = 315$ MHz,  $T_A = -40^{\circ}$ C to +85°C, unless otherwise noted. Typical values are at  $V_{DD} = 3.3V$  and  $T_A = +25^{\circ}$ C.) (Note 1).

PARAMETER	SYMBOL	CONDITIONS		MIN TYP	MAX	UNITS	
LO Signal Feedthrough to Antenna				-80		dBm	
Noise Figure	NF <sub>LNA</sub>			2		dB	
LNA IN LOW-GAIN MODE	,						
			f <sub>RF</sub> = 433MHz	1 - j3.4			
nput Impedance (Note 4)	Z <sub>IN_LNA</sub>	Normalized to $50\Omega$	f <sub>RF</sub> = 375MHz	1 - j3.9			
			f <sub>RF</sub> = 315MHz	1 - j4.7			
1dB Compression Point	P1dB <sub>LNA</sub>			-10		dBm	
Input-Referred 3rd-Order Intercept	IIP3 <sub>LNA</sub>			-7		dBm	
LO Signal Feedthrough to Antenna				-80		dBm	
Noise Figure	NF <sub>LNA</sub>			2		dB	
Power Gain				0		dB	
Voltage Gain Reduction		AGC enabled (deper	nds on tank Q)	35		dB	
MIXER				•			
Input-Referred 3rd-Order Intercept	IIP3 <sub>MIX</sub>			-18		dBm	
Output Impedance	Z <sub>OUT_MIX</sub>			330		Ω	
Noise Figure	NF <sub>MIX</sub>			16		dB	
		f <sub>RF</sub> = 433MHz, V <sub>IRS</sub>	EL = AV <sub>DD</sub>	42			
Image Rejection (not Including LNA Tank)		f <sub>RF</sub> = 375MHz, V <sub>IRSEL</sub> = AV <sub>DD</sub> /2		44		dB	
		f <sub>RF</sub> = 315MHz, V <sub>IRSEL</sub> = 0V		44			
Conversion Gain		330Ω IF filter load		13		dB	
INTERMEDIATE FREQUENCY (IF)				•			
Input Impedance	Z <sub>IN_IF</sub>			330		Ω	
Operating Frequency	f <sub>IF</sub>	Bandpass response		10.7		MHz	
3dB Bandwidth				20		MHz	
RSSI Linearity				±0.5		dB	
RSSI Dynamic Range				80		dB	
<b>DOOI I I I I</b>		P <sub>RFIN</sub> < -120dBm		1.15			
RSSI Level		P <sub>RFIN</sub> > 0dBm, AGC	enabled	2.35		- V	
RSSI Gain				14.2		mV/dB	
		LNA gain from low to	high	1.45		.,	
AGC Threshold		LNA gain from high t	o low	2.05		- V	

## 315MHz/433MHz ASK Superheterodyne Receiver with Extended Dynamic Range

### **AC Electrical Characteristics (continued)**

(*Typical Application Circuit*,  $AV_{DD} = DV_{DD} = V_{DD5} = 3.0V$  to 3.6V, all RF inputs are referenced to 50 $\Omega$ , f<sub>RF</sub> = 315MHz, T<sub>A</sub> = -40°C to +85°C, unless otherwise noted. Typical values are at V<sub>DD</sub> = 3.3V and T<sub>A</sub> = +25°C.) (Note 1).

PARAMETER	SYMBOL	cc	NDITIONS	MIN	TYP	MAX	UNITS
DATA FILTER		1					
Maximum Bandwidth	BW <sub>DF</sub>				100		kHz
DATA SLICER							
Comparator Bandwidth	BWCMP				100		kHz
Output High Voltage					V <sub>DD5</sub>		V
Output Low Voltage					0		V
CRYSTAL OSCILLATOR		-					-
	f <sub>XTAL</sub>	f <sub>RF</sub> = 433MHz	V <sub>XTALSEL</sub> = 0V		6.6128		- MHz
Orietal Francianas (Nata F)			V <sub>XTALSEL</sub> = AV <sub>DD</sub>		13.2256	;	
Crystal Frequency (Note 5)		f <sub>RF</sub> = 315MHz	V <sub>XTALSEL</sub> = 0V		4.7547		– MHz
			V <sub>XTALSEL</sub> = AV <sub>DD</sub>		9.5094		
Crystal Tolerance					50		ppm
Input Capacitance		From each pin to	ground		6.2		pF
Recommended Crystal Load Capacitance	C <sub>LOAD</sub>				3		pF
Maximum Crystal Load Capacitance	C <sub>LOAD</sub>				10		pF

**Note 1:** Note 1: 100% tested at  $T_A = +25^{\circ}C$ . Guaranteed by design and characterization over temperature.

Note 2: IRSEL is internally set to 375MHz IR mode. It can be left open when the 375MHz image rejection setting is desired. A 1nF capacitor is recommended in noisy environments.

Note 3: BER = 2 x 10<sup>-3</sup>, Manchester encoded, data rate = 4kbps, IF bandwidth = 280kHz.

- Note 4: Input impedance is measured at the LNAIN pin. Note that the impedance includes the 15nH inductive degeneration connected from the LNA source to ground. The equivalent input circuit is 50Ω in series with 2.2pF.
- Note 5: Crystal oscillator frequency for other RF carrier frequency within the 300MHz to 450MHz range is (f<sub>RF</sub> 10.7MHz)/64 for XTALSEL = 0V, and (f<sub>RF</sub> 10.7MHz)/32 for XTALSEL = AV<sub>DD</sub>.

## 315MHz/433MHz ASK Superheterodyne Receiver with Extended Dynamic Range

#### **Typical Operating Characteristics**

(Typical Application Circuit, V<sub>DD</sub> = 3.3V, f<sub>RF</sub> = 315MHz, T<sub>A</sub> = +25°C, unless otherwise noted.)



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## 315MHz/433MHz ASK Superheterodyne Receiver with Extended Dynamic Range

### **Typical Operating Characteristics (continued)**

(Typical Application Circuit, V<sub>DD</sub> = 3.3V, f<sub>RF</sub> = 315MHz, T<sub>A</sub> = +25°C, unless otherwise noted.)



## 315MHz/433MHz ASK Superheterodyne Receiver with Extended Dynamic Range

### **Pin Description**

PI	PIN NAME		FUNCTION					
TSSOP	TQFN	NANE	FUNCTION					
1	29	XTAL1	1st Crystal Input. (See the Phase-Locked Loop section.)					
2, 7	4, 30	AVDD	Positive Analog Supply Voltage. For +5V operation, pin 2 (TSSOP package) is the output of an on- chip +3.2V low-dropout regulator and should be bypassed to AGND with a 0.1 $\mu$ F capacitor as close as possible to the pin. Pin 7 must be externally connected to the supply from pin 2 and bypassed to AGND with a 0.01 $\mu$ F capacitor as close as possible to the pin (see the <i>Voltage Regulator</i> section and the <i>Typical Application Circuit</i> ).					
3	31	LNAIN	Low-Noise Amplifier Input. (See the Low-Noise Amplifier section.)					
4	32	LNASRC	Low-Noise Amplifier Source for External Inductive Degeneration. Connect inductor to ground to set LNA input impedance. (See the <i>Low-Noise Amplifier</i> section.)					
5	2	AGND	Analog Ground					
6	3	LNAOUT	Low-Noise Amplifier Output. Connect to mixer through an LC tank filter. (See the <i>Low-Noise Amplifier</i> section.)					
8	5	MIXIN1	1st Differential Mixer Input. Connect through a 100pF capacitor to LC tank filter from LNAOUT.					
9	6	MIXIN2	2nd Differential Mixer Input. Connect through a 100pF capacitor to AV <sub>DD</sub> side of the LC tank.					
10	7	AGND	Analog Ground					
11	8	IRSEL	Image Rejection Select Pin. Set $V_{IRSEL}$ = 0V to center image rejection at 315MHz. Leave IRSEL unconnected to center image rejection at 375MHz. Set $V_{IRSEL}$ = AV <sub>DD</sub> to center image rejection at 433MHz. Input logic level based on AV <sub>DD</sub> , ~3.2V supply.					
12	9	MIXOUT	330Ω Mixer Output. Connect to the input of the 10.7MHz bandpass filter.					
13	10	DGND	Digital Ground					
14	11	DVDD	Positive Digital Supply Voltage. Connect to both of the AVDD pins. Bypass to DGND with a 0.01µF capacitor as close as possible to the pin (see the <i>Typical Application Circuit</i> ).					
15	12	AGCDIS	AGC Control Pin. Pull high to disable AGC. Input logic level based on $V_{DD5}$ voltage.					
16	14	XTALSEL	Crystal Divider Ratio Select Pin. Drive XTALSEL low to select divider ratio of 64, or drive XTALSEL high to select divider ratio of 32. Input logic level based on AV <sub>DD</sub> , ~3.2V supply.					
17	15	IFIN1	1st Differential Intermediate Frequency Limiter Amplifier Input. Decouple to AGND with a 1500pF capacitor.					
18	16	IFIN2	2nd Differential Intermediate Frequency Limiter Amplifier Input. Connect to the output of a 10.7MHz bandpass filter.					
19	17	DFO	Data Filter Output					
20	18	DSN	Negative Data Slicer Input					
21	19	OPP	Noninverting Op-Amp Input for the Sallen-Key Data Filter					
22	20	DFFB	Data Filter Feedback Node. Input for the feedback of the Sallen-Key data filter.					
23	22	DSP	Positive Data Slicer Input					
24	23	V <sub>DD5</sub>	+5V Supply Voltage. Bypass to AGND with a $0.01\mu$ F capacitor as close as possible to the pin. For +5V operation, V <sub>DD5</sub> is the input to an on-chip voltage regulator whose +3.2V output appears at the pin 2 AVDD pin. (See the <i>Voltage Regulator</i> section and the <i>Typical Application Circuit</i> .)					
25	24	DATAOUT	Digital Baseband Data Output. Output logic level based on V <sub>DD5</sub> voltage.					
26	26	PDOUT	Peak Detector Output					
27	27	PWRDN	Power-Down Select Input. Drive this pin with a logic high to power on the IC. Input logic level based on V <sub>DD5</sub> voltage.					
28	28	XTAL2	2nd Crystal Input					
_	1, 13, 21, 25	N.C.	No Connection					
—	_	EP	Exposed Pad (TQFN Only). Connect EP to GND.					

## 315MHz/433MHz ASK Superheterodyne Receiver with Extended Dynamic Range

#### **Detailed Description**

The MAX1473 CMOS superheterodyne receiver and a few external components provide the complete receive chain from the antenna to the digital output data. Depending on signal power and component selection, data rates as high as 100kbps can be achieved. The MAX1473 is designed to receive binary ASK data modulated in the 300MHz to 450MHz frequency range. ASK modulation uses a difference in amplitude of the carrier to represent logic 0 and logic 1 data.

#### **Voltage Regulator**

For operation with a single +3.0V to +3.6V supply voltage, connect AVDD, DVDD, and V<sub>DD5</sub> to the supply voltage. For operation with a single +4.5V to +5.5V supply voltage, connect V<sub>DD5</sub> to the supply voltage. An on-chip voltage regulator drives one of the AVDD pins to approximately +3.2V. For proper operation, DVDD and both the AVDD pins must be connected together. Bypass V<sub>DD5</sub>, DVDD, and the pin 7 AVDD pin to AGND with 0.01µF capacitors, and the pin 2 AVDD pin to AGND with a 0.1µF capacitor, all placed as close as possible to the pins.

#### Low-Noise Amplifier

The LNA is an NMOS cascode amplifier with off-chip inductive degeneration that achieves approximately 16dB of power gain with a 2.0dB noise figure and an IIP3 of -12dBm. The gain and noise figure are dependent on both the antenna matching network at the LNA input and the LC tank network between the LNA output and the mixer inputs.

The off-chip inductive degeneration is achieved by connecting an inductor from LNASRC to AGND. This inductor sets the real part of the input impedance at LNAIN, allowing for a more flexible input impedance match, such as a typical PCB trace antenna. A nominal value for this inductor with a 50 $\Omega$  input impedance is 15nH, but is affected by PCB trace. See the *Typical Operating Characteristics* for the relationship between the inductance and the LNA input impedance.

The AGC circuit monitors the RSSI output. When the RSSI output reaches 2.05V, which corresponds to an RF input level of approximately -57dBm, the AGC switches on the LNA gain reduction resistor. The resistor reduces the LNA gain by 35dB, thereby reducing the RSSI output by about 500mV. The LNA resumes high-gain mode when the RSSI level drops back below 1.45V (approximately -65dBm at RF input) for 150ms. The AGC has a hysteresis of ~8dB. With the AGC function, the MAX1473 can reliably produce an ASK output for RF input levels up to 0dBm with a modulation depth of 18dB.

The LC tank filter connected to LNAOUT comprises L3 and C2 (see the *Typical Application Circuit*). Select L3 and C2 to resonate at the desired RF input frequency. The resonant frequency is given by:

$$f = \frac{1}{2\pi\sqrt{L_{TOTAL} \times C_{TOTAL}}}$$

where:

LTOTAL = L3 + LPARASITICS

C<sub>TOTAL</sub> = C2 + C<sub>PARASITICS</sub>

LPARASITICS and CPARASITICS include inductance and capacitance of the PCB traces, package pins, mixer input impedance, LNA output impedance, etc. These parasitics at high frequencies cannot be ignored, and can have a dramatic effect on the tank filter center frequency. Lab experimentation should be done to optimize the center frequency of the tank.

#### Mixer

A unique feature of the MAX1473 is the integrated image rejection of the mixer. This device eliminates the need for a costly front-end SAW filter for most applications. Advantages of not using a SAW filter are increased sensitivity, simplified antenna matching, less board space, and lower cost.

The mixer cell is a pair of double balanced mixers that perform an IQ downconversion of the RF input to the 10.7MHz IF from a low-side injected LO (i.e.,  $f_{LO} = f_{RF} - f_{IF}$ ). The image-rejection circuit then combines these signals to achieve a minimum 45dB of image rejection over the full temperature range. Low-side injection is required due to the on-chip image rejection architecture. The IF output is driven by a source-follower biased to create a driving impedance of 330 $\Omega$ ; this provides a good match to the off-chip 330 $\Omega$  ceramic IF filter. The voltage conversion gain is approximately 13dB when the mixer is driving a 330 $\Omega$  load.

The IRSEL pin is a logic input that selects one of the three possible image-rejection frequencies. The input logic level is based on the AV<sub>DD</sub>, supply voltage generated by the on-chip voltage regulator (~3.2V). When V<sub>IRSEL</sub> = 0V, the image rejection is tuned to 315MHz. V<sub>IRSEL</sub> = AV<sub>DD</sub>/2 tunes the image rejection to 375MHz, and when V<sub>IRSEL</sub> = AV<sub>DD</sub>, the image rejection is tuned to 433MHz. The IRSEL pin is internally set to AV<sub>DD</sub>/2 (image rejection at 375MHz) when it is left unconnected, thereby eliminating the need for an external AV<sub>DD</sub>/2 voltage.

#### **Phase-Locked Loop**

The PLL block contains a phase detector, charge pump/ integrated loop filter, VCO, asynchronous 64x clock divider, and crystal oscillator driver. Besides the crystal, this PLL does not require any external components. The VCO generates a low-side local oscillator (LO). The relationship between the RF, IF, and crystal reference frequencies is given by:

$$f_{XTAL} = (f_{RF} - f_{IF})/(32 \times M)$$

where:

 $M = 1 (V_{XTALSEL} = AV_{DD}) \text{ or } 2 (V_{XTALSEL} = 0V)$ 

To allow the smallest possible IF bandwidth (for best sensitivity), the tolerance of the reference must be minimized.

#### Intermediate Frequency/RSSI

The IF section presents a differential  $330\Omega$  load to provide matching for the off-chip ceramic filter. The six internal AC-coupled limiting amplifiers produce an overall gain of approximately 65dB, with a bandpass filter-type response centered near the 10.7MHz IF frequency with a 3dB bandwidth of approximately 11.5MHz. The RSSI circuit demodulates the IF by producing a DC output proportional to the log of the IF signal level, with a slope of approximately 14.2mV/dB (see the *Typical Operating Characteristics*).

The AGC circuit monitors the RSSI output. When the RSSI output reaches 2.05V, which corresponds to an RF input level of approximately -57dBm, the AGC switches on the LNA gain reduction resistor. The resistor reduces the LNA gain by 35dB, thereby reducing the RSSI output by about 500mV. The LNA resumes high-gain mode when the RSSI level drops back below 1.45V (approximately -65dBm at RF input) for 150ms. The AGC has a hysteresis of ~8dB. With the AGC function, the MAX1473 can reliably produce an ASK output for RF input levels up to 0dBm with modulation depth of 18dB.

#### **Applications Information**

#### **Crystal Oscillator**

The XTAL oscillator in the MAX1473 is designed to present a capacitance of approximately 3pF between the XTAL1 and XTAL2. If a crystal designed to oscillate with a different load capacitance is used, the crystal is pulled away from its stated operating frequency, introducing an error in the reference frequency. Crystals designed to operate with higher differential load capacitance always pull the reference frequency higher. For example, a 4.7547MHz crystal designed to operate with a 10pF load capacitance oscillates at 4.7563MHz with the MAX1473,

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causing the receiver to be tuned to 315.1MHz rather than 315.0MHz, an error of about 100kHz, or 320ppm.

In actuality, the oscillator pulls every crystal. The crystal's natural frequency is really below its specified frequency, but when loaded with the specified load capacitance, the crystal is pulled and oscillates at its specified frequency. This pulling is already accounted for in the specification of the load capacitance.

Additional pulling can be calculated if the electrical parameters of the crystal are known. The frequency pulling is given by:

$$f_{p} = \frac{C_{m}}{2} \left( \frac{1}{C_{case +} C_{load}} - \frac{1}{C_{case +} C_{spec}} \right) \times 10^{6}$$

where:

fp is the amount the crystal frequency pulled in ppm.

C<sub>m</sub> is the motional capacitance of the crystal.

C<sub>case</sub> is the case capacitance.

C<sub>spec</sub> is the specified load capacitance.

Cload is the actual load capacitance.

When the crystal is loaded as specified, i.e.,  $C_{load} = C_{spec}$ , the frequency pulling equals zero.

#### **Data Filter**

The data filter is implemented as a 2nd-order lowpass Sallen-Key filter. The pole locations are set by the combination of two on-chip resistors and two external capacitors. Adjusting the value of the external capacitors changes the corner frequency to optimize for different data rates. The corner frequency should be set to approximately 1.5 times the fastest expected data rate from the transmitter. Keeping the corner frequency near the data rate rejects any noise at higher frequencies, resulting in an increase in receiver sensitivity.

The configuration shown in Figure 1 can create a Butterworth or Bessel response. The Butterworth filter offers a very flat amplitude response in the passband and a rolloff rate of 40dB/decade for the two-pole filter. The Bessel filter has a linear phase response, which works well for filtering digital data. To calculate the value of C7 and C6, use the following equations along with the coefficients in Table 1:

#### Table 1. Coefficients to Calculate C7 and C6

FILTER TYPE	а	b
Butterworth (Q = 0.707)	1.414	1.000
Bessel (Q = 0.577)	1.3617	0.618

$$C7 = \frac{b}{a(100k)(\pi)(f_c)}$$
$$C6 = \frac{a}{4(100k)(\pi)(f_c)}$$

where f<sub>C</sub> is the desired 3dB corner frequency.

For example, choose a Butterworth filter response with a corner frequency of 5kHz:

$$C7 = \frac{1.000}{(1.414)(100k\Omega)(3.14)(5kHz)} \approx 450 pF$$

Choosing standard capacitor values changes C7 to 470pF and C6 to 220pF, as shown in the *Typical Application Circuit*.



Figure 1. Sallen-Key Lowpass Data Filter



Figure 2. Generating Data Slicer Threshold

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#### **Data Slicer**

The purpose of the data slicer is to take the analog output of the data filter and convert it to a digital signal. This is achieved by using a comparator and comparing the analog input to a threshold voltage. The output logic level is based on  $V_{DD5}$  voltage supply. One input is supplied by the data filter output. Both comparator inputs are accessible off chip to allow for different methods of generating the slicing threshold, which is applied to the second comparator input.

The suggested data slicer configuration uses a resistor (R1) connected between DSN and DSP with a capacitor (C8) from DSN to DGND (Figure 2). This configuration averages the analog output of the filter and sets the threshold to approximately 50% of that amplitude. With this configuration, the threshold automatically adjusts as the analog signal varies, minimizing the possibility for errors in the digital data. The sizes of R1 and C8 affect how fast the threshold tracks to the analog amplitude. Be sure to keep the corner frequency of the RC circuit much lower than the lowest expected data rate.

Note that a long string of zeros or 1s can cause the threshold to drift. This configuration works best if a coding scheme, such as Manchester coding, which has an equal number of zeros and 1s, is used.

To prevent continuous toggling of DATAOUT in the absence of an RF signal due to noise, hysteresis can be added to the data slicer as shown in Figure 3.

For further information on Data Slicer options, please refer to Maxim Application Note 3671, *Data Slicing Techniques* 



Figure 3. Generating Data Slicer Hysteresis

## 315MHz/433MHz ASK Superheterodyne Receiver with Extended Dynamic Range

for UHF ASK Receivers.

#### **Peak Detector**

The peak detector output (PDOUT), in conjunction with an external RC filter, creates a DC output voltage equal to the peak value of the data signal. The resistor provides a path for the capacitor to discharge, allowing the peak detector to dynamically follow peak changes of the data filter output voltage. For faster receiver startup, the circuit shown in Figure 4 can be used.

#### Layout Considerations

A properly designed PCB is an essential part of any RF/ microwave circuit. On high-frequency inputs and outputs, use controlled-impedance lines and keep them as short as possible to minimize losses and radiation. At high frequencies, trace lengths that are on the order of  $\lambda$ /10 or longer act as antennas.

Keeping the traces short also reduces parasitic inductance. Generally, 1in of a PCB trace adds about 20nH of parasitic inductance. The parasitic inductance can have a dramatic effect on the effective inductance of a passive component. For example, a 0.5in trace connecting a 100nH inductor adds an extra 10nH of inductance or 10%.

To reduce the parasitic inductance, use wider traces and a solid ground or power plane below the signal traces. Also, use low-inductance connections to ground on all GND pins, and place decoupling capacitors close to all power-supply pins.



Figure 4. Using PDOUT for Faster Startup

#### **Control Interface Considerations**

When operating the MAX1473 with a +4.5V to +5.5V supply voltage, the PWRDN and AGCDIS pins may be driven by a microcontroller with either 3V or 5V interface logic levels. When operating the MAX1473 with a +3.0V to +3.6V supply, the microcontroller must produce logic levels which conform to the V<sub>IH</sub> and V<sub>IL</sub> specifications in the *DC Electrical Characteristics Table* for the MAX1473.

## 315MHz/433MHz ASK Superheterodyne Receiver with Extended Dynamic Range

COMPONENT	VALUE FOR f <sub>RF</sub> = 433MHz	VALUE FOR f <sub>RF</sub> = 315MHz	DESCRIPTION
C1	100pF	100pF	5%
C2	2.7pF	4.7pF	±0.1pF
C3	100pF	100pF	5%
C4	100pF	100pF	5%
C5	1500pF	1500pF	10%
C6	220pF	220pF	5%
C7	470pF	470pF	5%
C8	0.47µF	0.47µF	20%
C9	220pF	220pF	10%
C10	0.01µF	0.01µF	20%
C11	0.1µF	0.1µF	20%
C12	15pF	15pF	Depends on XTAL
C13	15pF	15pF	Depends on XTAL
C14	0.01µF	0.01µF	20%
C15	0.01µF	0.01µF	20%
L1	56nH	120nH	5% or better**
L2	15nH	15nH	5% or better**
L3	15nH	27nH	5% or better**
R1	5.1kΩ	5.1kΩ	5%
R2	Open	Open	_
R3	Short	Short	_
X1(÷64)	6.6128MHz*	4.7547MHz*	Crystek or Hong Kong X'tal
X1 (÷32)	13.2256MHz*	9.5094MHz*	Crystek or Hong Kong X'tal
Y1	10.7MHz ceramic filter	10.7MHz ceramic filter	Murata

### **Table 2. Component Values for Typical Application Circuit**

\*Crystal frequencies shown are for  $\div$ 64 (V<sub>XTALSEL</sub> = 0V) and  $\div$ 32 (V<sub>XTALSEL</sub> = V<sub>DD</sub>). \*\*Wirewound recommended.

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### **Typical Application Circuit**



Chip Information PROCESS: CMOS

# 315MHz/433MHz ASK Superheterodyne Receiver with Extended Dynamic Range

#### IRSEL MIXOUT LNASRC AGCDIS LNAOUT MIXIN1 MIXIN2 IFIN1 IFIN2 41 15 6| 8| 9| 11 12 17 18 0° IF LIMITING AUTOMATIC LNAIN <u>3</u> AMPS LNA GAIN IMAGE Σ CONTROL REJECTION 90° AVDD **MAX1473** 3.2V REG RSSI 24 V<sub>DD5</sub> AVDD DATA DIVIDE dvdd $\frac{14}{14}$ VCO FILTER BY 64 R<sub>DF2</sub> 100kΩ R<sub>DF1</sub> ¥ 4 $100 k\Omega$ PHASE LOOP DGND $\frac{13}{13}$ ١A. FILTER DETECTOR DATA AGND<sup>5,<u>10</u></sup> SLICER CRYSTAL POWER 2 DRIVER DOWN 27 25 16 28 20 23 19 26 21 22 1 XTALSEL XTAL1 XTAL2 PWRDN DATAOUT DSN DSP DFO PDOUT OPP DFFB

### **Functional Diagram**

#### **Package Information**

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
28 TSSOP	U28+1	<u>21-0066</u>	<u>90-0171</u>
32 Thin QFN-EP	T3255+3	<u>21-0140</u>	<u>90-0001</u>

## 315MHz/433MHz ASK Superheterodyne Receiver with Extended Dynamic Range

### **Revision History**

REVISION NUMBER	REVISION DATE	DESCRIPTION	PAGES CHANGED
4	5/10	Added lead-free parts and exposed pad in Ordering Information and Pin Description tables	1, 8
5	1/11	Updated Absolute Maximum Ratings, AC Electrical Characteristics, Pin Description, Layout Considerations, Typical Application Circuit, Functional Diagram, and Package Information; added Voltage Regulator section to the Detailed Description section	2, 3, 4, 8, 9, 12, 13, 14
6	1/12	Updated <i>DC Electrical</i> and <i>AC Electrical Characteristics</i> tables, replaced TOC 4, updated Tables 1 and 2 and Figure 1; updated <i>Phase-Locked Loop</i> , <i>Data Filter</i> , <i>Data Slicer</i> , and <i>Layout Considerations</i> sections	3, 5, 6, 10–13
7	1/19	Updated Absolute Maximum Ratings, DC Electrical Characteristics, DC Electrical Characteristics, Pin Description table, Detailed Description, and Typical Application Circuit	2–5, 8–11, 14

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